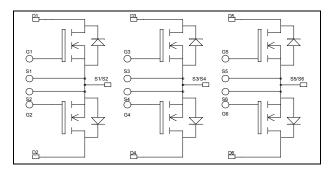


# Triple dual Common Source Super Junction MOSFET Power Module



$$\begin{split} V_{DSS} &= 800V \\ R_{DSon} &= 150 m\Omega \ max \ @ \ Tj = 25^{\circ}C \\ I_D &= 28A \ @ \ Tc = 25^{\circ}C \end{split}$$

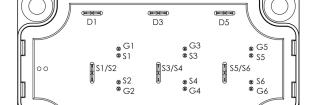
### **Application**

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

#### **Features**



- Ultra low R<sub>DSon</sub>
  - Low Miller capacitance
  - Ultra low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - Lead frames for power connections
- High level of integration



### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Each leg can be easily paralleled to achieve a dual common source configuration of three times the current capability
- RoHS Compliant

### **Absolute maximum ratings**

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		800	V
Ţ	Continuous Drain Current	$T_c = 25^{\circ}C$	28	
$I_{\mathrm{D}}$		$T_c = 80$ °C	21	A
$I_{DM}$	Pulsed Drain current		110	
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		150	mΩ
$P_{D}$	Maximum Power Dissipation $T_c = 25^{\circ}C$		277	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		17	A
$E_{AR}$	Repetitive Avalanche Energy		0.5	I
$E_{AS}$	Single Pulse Avalanche Energy		670	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 800V$ $T_j = 25^{\circ}C$			50	μА
		$V_{GS} = 0V, V_{DS} = 800V$ $T_j = 125^{\circ}C$			375	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 14A$			150	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 2mA$	2.1	3	3.9	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

**Dynamic Characteristics** 

•	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		4507		
$C_{oss}$	Output Capacitance	$V_{\rm DS} = 25V$		2092		pF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		108		
$Q_{g}$	Total gate Charge	$V_{GS} = 10V$		180		
$Q_{gs}$	Gate – Source Charge	$V_{\text{Bus}} = 400V$		22		nC
$Q_{\text{gd}}$	Gate – Drain Charge	$I_D = 28A$		90		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @125°C		10		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		13		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 533 \text{V}$ $I_{\text{D}} = 28 \text{A}$		83		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.5\Omega$		35		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		486		т
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 28A, R_G = 2.5\Omega$		278		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		850		т
E <sub>off</sub>	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 28A, R_G = 2.5\Omega$		342		μJ

### **Source - Drain diode ratings and characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I <sub>S</sub>	Continuous Source current		$Tc = 25^{\circ}C$	1,200	28	1/24/04	
5	(Body diode)		$Tc = 80^{\circ}C$		21		Α
$V_{\mathrm{SD}}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -28A$				1.2	V
dv/dt	Peak Diode Recovery •					6	V/ns
$t_{rr}$	Reverse Recovery Time	$I_S = -28A$	$T_j = 25^{\circ}C$		550		ns
$Q_{rr}$	Reverse Recovery Charge	$V_R = 400V$ $di_S/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		30		μС

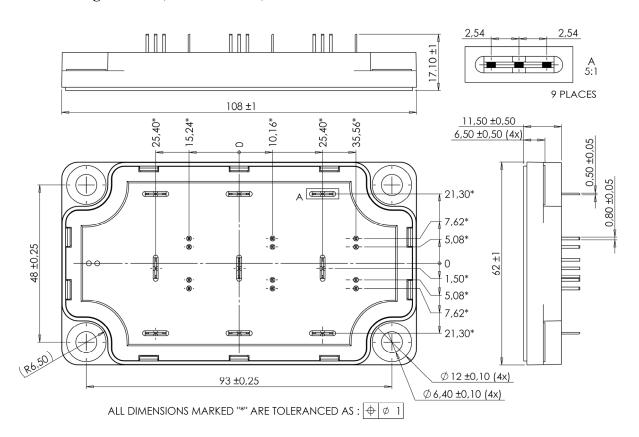
• dv/dt numbers reflect the limitations of the circuit rather than the device itself.



### Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
$R_{thJC}$	Junction to Case Thermal Resistance					0.45	°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range		-40		150		
$T_{STG}$	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight	·				250	g

## SP6-P Package outline (dimensions in mm)

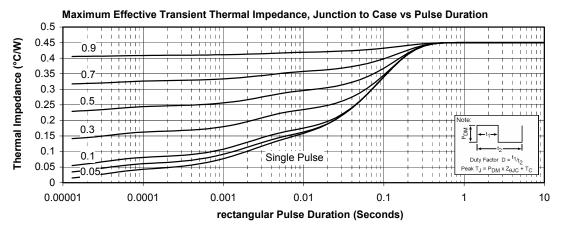


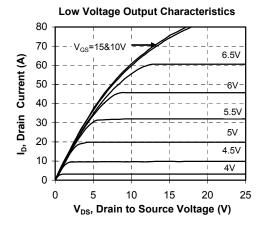
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

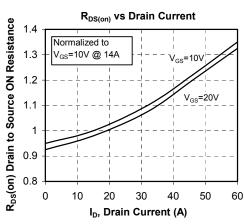
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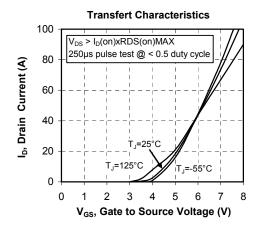


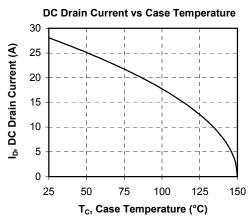
### **Typical Performance Curve**





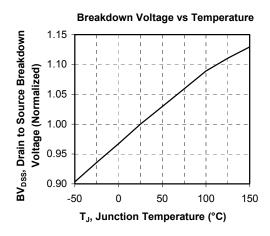


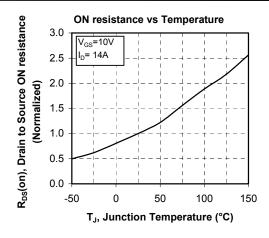


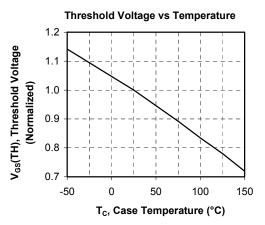


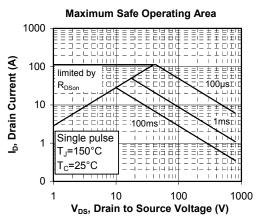
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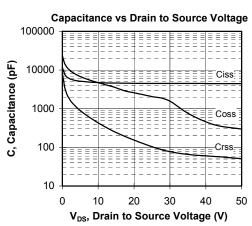


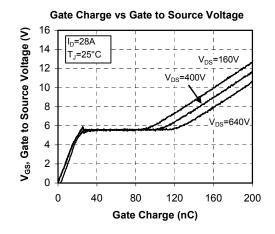




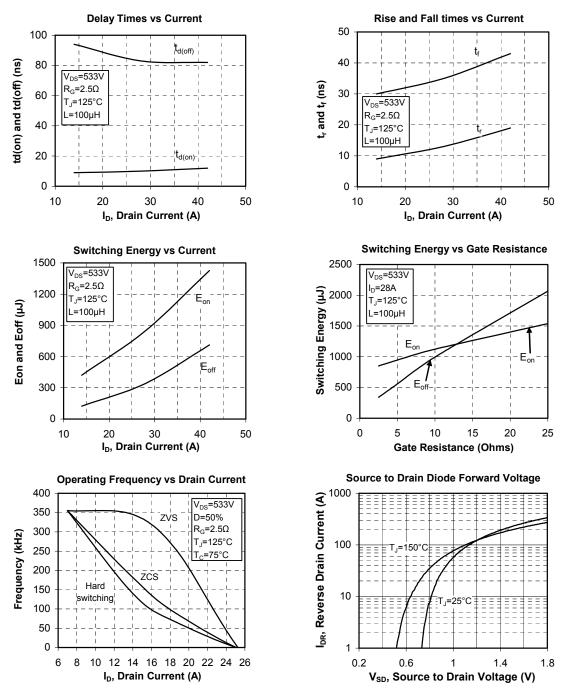












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